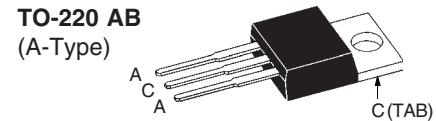
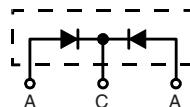


# Power Schottky Rectifier with common cathode

## Preliminary Data

| $V_{RSM}$ | $V_{RRM}$ | Type         |
|-----------|-----------|--------------|
| V         | V         |              |
| 100       | 100       | DSSK 16-01A  |
| 100       | 100       | DSSK 16-01AS |



A = Anode, C = Cathode , TAB = Cathode

| Symbol         | Test Conditions   | Maximum Ratings |                        |
|----------------|---|-----------------|------------------------|
| $I_{FRMS}$     |   | 35              | A                      |
| $I_{FAV}$      | $T_c = 165^\circ\text{C}$ ; rectangular, $d = 0.5$  | 8               | A                      |
| $I_{FAV}$      | $T_c = 165^\circ\text{C}$ ; rectangular, $d = 0.5$ ; per device                               | 16              | A                      |
| $I_{FSM}$      | $T_{VJ} = 45^\circ\text{C}$ ; $t_p = 10 \text{ ms}$ (50 Hz), sine                             | 120             | A                      |
| $E_{AS}$       | $I_{AS} = 8 \text{ A}$ ; $L = 180 \mu\text{H}$ ; $T_{VJ} = 25^\circ\text{C}$ ; non repetitive | 7               | mJ                     |
| $I_{AR}$       | $V_A = 1.5 \cdot V_{RRM}$ typ.; $f=10 \text{ kHz}$ ; repetitive                               | 0.8             | A                      |
| $(dv/dt)_{cr}$ |   | 5000            | $\text{V}/\mu\text{s}$ |
| $T_{VJ}$       |   | -55...+175      | $^\circ\text{C}$       |
| $T_{VJM}$      |   | 175             | $^\circ\text{C}$       |
| $T_{stg}$      |   | -55...+150      | $^\circ\text{C}$       |
| $P_{tot}$      | $T_c = 25^\circ\text{C}$  | 90              | W                      |
| $M_d$          | mounting torque (Version A only)  | 0.4...0.6       | Nm                     |
| Weight         | typical   | 2               | g                      |

### Features

- International standard package
- Very low  $V_F$
- Extremely low switching losses
- Low  $I_{RM}$ -values
- Epoxy meets UL 94V-0

### Applications

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

### Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses

Dimensions see pages D2 - 87-88

| Symbol                   | Test Conditions  | Characteristic Values |                   |
|--------------------------|--|-----------------------|-------------------|
|                          |  | typ.                  | max.              |
| $I_R$ ①                  | $T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$<br>$T_{VJ} = 125^\circ\text{C}$ $V_R = V_{RRM}$  | 0.3<br>2.5            | mA<br>mA          |
| $V_F$                    | $I_F = 10 \text{ A}$ ; $T_{VJ} = 125^\circ\text{C}$<br>$I_F = 10 \text{ A}$ ; $T_{VJ} = 25^\circ\text{C}$<br>$I_F = 20 \text{ A}$ ; $T_{VJ} = 125^\circ\text{C}$ | 0.65<br>0.80<br>0.77  | V<br>V<br>V       |
| $R_{thJC}$<br>$R_{thCH}$ | (Version A only)   | 0.5                   | 1.7<br>K/W<br>K/W |

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %

Data according to IEC 60747 and per diode unless otherwise specified.

IXYS reserves the right to change limits, Conditions and dimensions.

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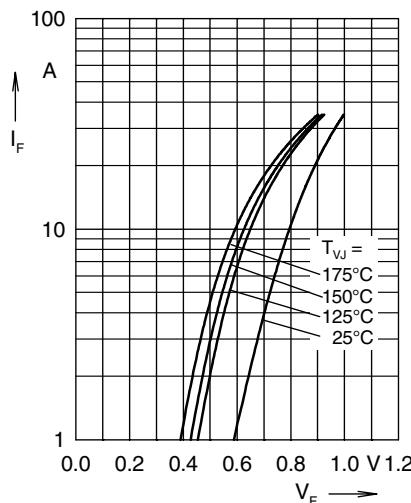


Fig. 1 Maximum forward voltage drop characteristics

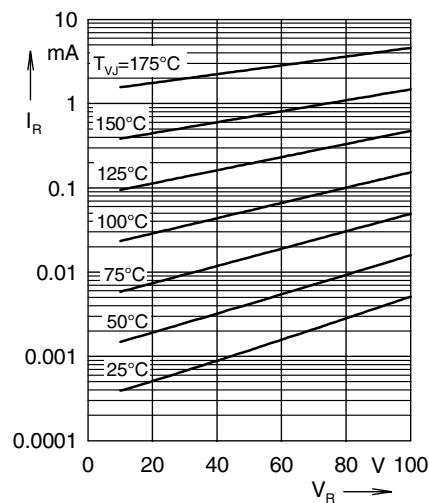


Fig. 2 Typ. value of reverse current  $I_R$  versus reverse voltage  $V_R$

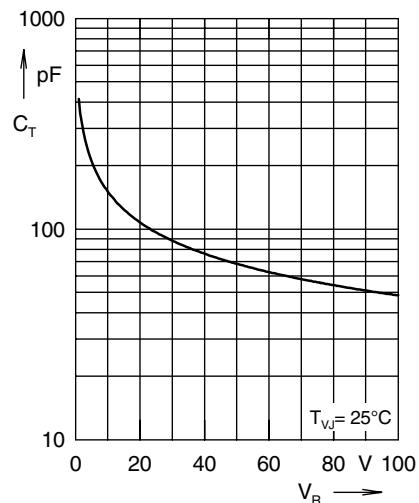


Fig. 3 Typ. junction capacitance  $C_T$  versus reverse voltage  $V_R$

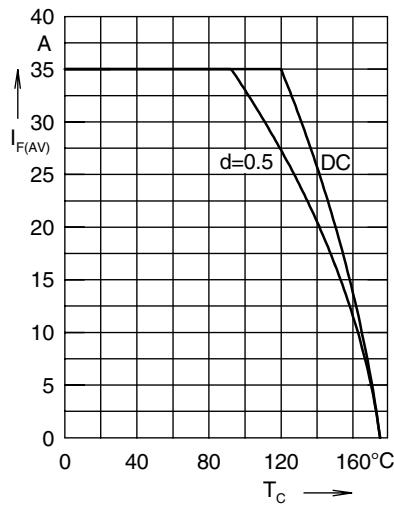


Fig. 4 Average forward current  $I_{F(AV)}$  versus case temperature  $T_C$

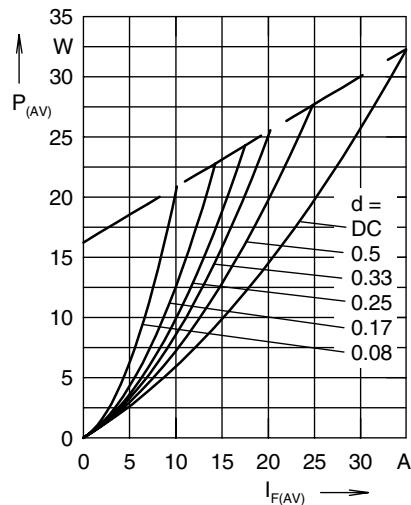


Fig. 5 Forward power loss characteristics

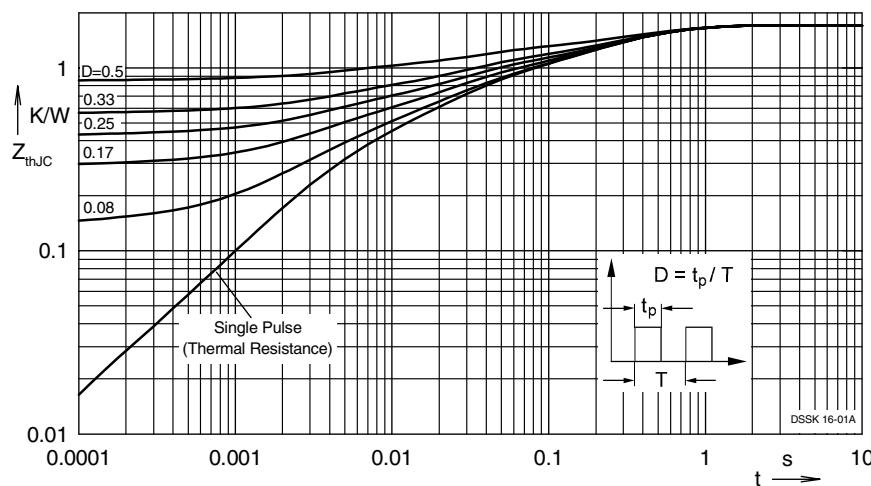


Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per Diode